Revision 0.53

# SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

#### General Product Information

| Product   | Application  |
|---|--------------|
| 1083 nm DFB Laser   | Spectroscopy |
| with hermetic 14 Pin-Butterfly Housing (RoHS compliant)       | Metrology    |
| including Monitor Diode, Thermoelectric Cooler and Thermistor | Magnetometer |
| with integrated Beam Collimation                              |              |

Measurement Conditions / Comments Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

#### Absolute Maximum Ratings

| Parameter                             | Symbol           | Unit | min | typ | max |
|---------------------------------------|------------------|------|-----|-----|-----|
| Storage Temperature                   | Ts               | °C   | -40 |     | 85  |
| Operational Temperature at Case       | T <sub>C</sub>   | °C   | -40 |     | 85  |
| Operational Temperature at Laser Chip | T <sub>LD</sub>  | °C   | 10  |     | 50  |
| Forward Current                       | I <sub>F</sub>   | mA   |     |     | 200 |
| Reverse Voltage                       | V <sub>R</sub>   | V    |     |     | 2   |
| Output Power                          | P <sub>opt</sub> | mW   |     |     | 90  |
| TEC Current                           | I <sub>TEC</sub> | А    |     |     | 1.1 |
| TEC Voltage                           | V <sub>TEC</sub> | V    |     |     | 2.8 |

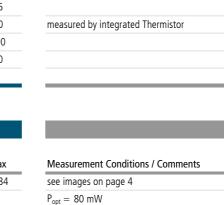
#### **Recommended Operational Conditions**

| Parameter                             | Symbol            | Unit | min | typ | max |
|---------------------------------------|-------------------|------|-----|-----|-----|
| Operational Temperature at Case       | T <sub>case</sub> | °C   | -20 |     | 65  |
| Operational Temperature at Laser Chip | T <sub>LD</sub>   | °C   | 15  |     | 40  |
| Forward Current                       | l <sub>F</sub>    | mA   |     |     | 190 |
| Output Power                          | P <sub>opt</sub>  | mW   | 20  |     | 80  |

#### Characteristics at T<sub>LD</sub> = 25° at BOL

| Parameter                             | Symbol         | Unit    | min  | typ   | max  |
|---------------------------------------|----------------|---------|------|-------|------|
| Center Wavelength                     | λ <sub>c</sub> | nm      | 1082 | 1083  | 1084 |
| Linewidth (FWHM)                      | Δλ             | MHz     |      | 2     |      |
| Sidemode Supression Ratio             | SMSR           | dB      | 30   | 45    |      |
| Temperature Coefficient of Wavelength | dλ / dT        | nm / K  |      | 0.06  |      |
| Current Coefficient of Wavelength     | dλ / dI        | nm / mA |      | 0.003 |      |

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Measurement Conditions / Comments

### $P_{opt} = 80 \text{ mW}$ $P_{opt} = 80 \text{ mW}$

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| Characteristics at $T_{LD}$ = 25° a          | at BOL           |       |     |     | cont'd |
|--|------------------|-------|-----|-----|--------|
| Parameter                                    | Symbol           | Unit  | min | typ | max    |
| Laser Current @ $P_{opt} = 80 \text{ mW}$    | I <sub>LD</sub>  | mA    |     |     | 190    |
| Slope Efficiency                             | η                | W / A | 0.6 | 0.8 | 1.0    |
| Threshold Current                            | I <sub>th</sub>  | mA    |     |     | 70     |
| Divergence parallel (FWHM)                   | $\Theta_{  }$    | 0     |     | 0.1 |        |
| Divergence perpendicular (FWHM)              | $\Theta_{\perp}$ | 0     |     | 0.1 |        |
| Beam Diameter horizontal (1/e <sup>2</sup> ) | d                | mm    |     | 1.0 | 1.2    |
| Beam Diameter vertical (1/e <sup>2</sup> )   | $d_{\bot}$       | mm    |     | 0.8 | 1.2    |
| Degree of Polarization                       | DOP              | %     |     | 90  |        |
|  |                  |       |     |     |        |

Measurement Conditions / Comments

parallel to the base plate of the housing (see p. 3) perpendicular to base plate of the housing (see p. 3) parallel to the base plate of the housing (see p. 3) perpendicular to base plate of the housing (see p. 3)  $P_{opt} = 80$  mW; E field parallel to the base plate

#### Monitor Diode

| Parameter                     | Symbol                              | Unit  | min | typ | max |
|-------------------------------|-------------------------------------|-------|-----|-----|-----|
| Monitor Detector Responsivity | I <sub>mon</sub> / P <sub>opt</sub> | µA/mW | 0.5 |     | 10  |

#### Thermoelectric Cooler

| Parameter                              | Symbol           | Unit | min | typ | max |
|--|------------------|------|-----|-----|-----|
| Current                                | I <sub>TEC</sub> | А    |     | 0.4 |     |
| Voltage                                | U <sub>TEC</sub> | V    |     | 0.8 |     |
| Power Dissipation (total loss at case) | Ploss            | W    |     | 0.4 |     |
| Temperature Difference                 | ΔΤ               | К    |     |     | 50  |

#### Thermistor (Standard NTC Type)

| Parameter                      | Symbol | Unit | min | typ         | max              |
|--------------------------------|--------|------|-----|-------------|------------------|
| Resistance                     | R      | kΩ   |     | 10          |                  |
| Beta Coefficient               | β      |      |     | 3892        |                  |
| Steinhart & Hart Coefficient A | А      |      |     | 1.1293 x 10 | #NV              |
| Steinhart & Hart Coefficient B | В      |      |     | 2.3410 x 10 | #NV              |
| Steinhart & Hart Coefficient C | С      |      |     | 8.7755 x 10 | ) <sup>#NV</sup> |
|                                |        |      |     |             |                  |

| Measurement Conditions / Comments |     |   |  |  |  |  |
|-----------------------------------|-----|---|--|--|--|--|
| $U_R =$                           | 5 V | Ì |  |  |  |  |

| Measurement Conditions / Comments                   |  |  |  |
|---|--|--|--|
| $P_{opt} = 80 \text{ mW}, \Delta T = 20 \text{ K}$  |  |  |  |
| $P_{opt} = 80 \text{ mW}, \Delta T = 20 \text{ K}$  |  |  |  |
| $P_{opt} = 80 \text{ mW}, \Delta T = 20 \text{ K}$  |  |  |  |
| $P_{opt} = 80 \text{ mW}, \Delta T =  Tcase - TLD $ |  |  |  |
|   |  |  |  |

| $T_{LD} = 25^{\circ} C$                                   |          |
|---|----------|
| $R_{1}/R_{2}=e^{\beta(1/T_{1}\cdot1/T_{2})}$ at $T_{LD}=$ | 0° 50° C |
| $1/T = A + B(\ln R) + C(\ln R)^{3}$                       |          |
| T: temperature in Kelvin                                  |          |
| R: resistance at T in Ohm                                 |          |

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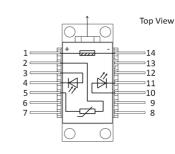
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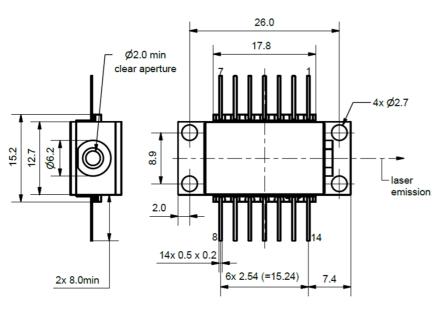
### Pin Assignment

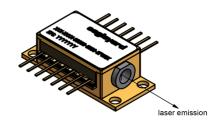
| 1    | Thermoelectric Cooler (+)                      | 14 | Thermoelectric Cooler (-) |
|------|--|----|---------------------------|
| 2    | Thermistor                                     | 13 | Case                      |
| 3    | Photodiode (Anode)                             | 12 | not connected             |
| 4    | Photodiode (Cathode)                           | 11 | Laser Diode (Cathode)     |
| 5    | Thermistor                                     | 10 | Laser Diode (Anode)       |
| 6    | not connected                                  | 9  | not connected             |
| 7    | not connected                                  | 8  | not connected             |
| Pins | are isolated from case unless noted otherwise. |    |                           |





22.2 20.8 emission 5.0 3.5 1.0 30.0 4.9





Caution. Excessive mechanical stress on the package can lead to a damage of the laser.

See <u>instruction manual</u> on www.eagleyard.com

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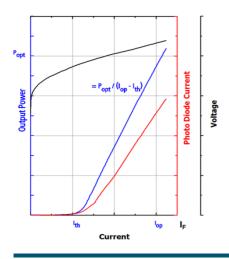
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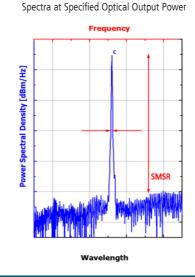
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### SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

#### Typical Measurement Results

#### Output Power vs. Current





Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The DFB laser is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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DIRECT OR SCATTERED RADIATION GaAs SEMICONDUCTOR LASER DIODE I mW MAX OUTPUT AT 1083 nm CLASS IV LASER PRODUCT th 21 CFR 1040.10 and 1040.40



